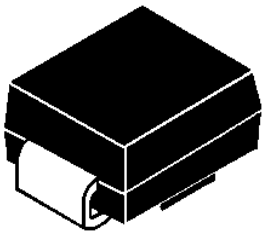
3000W Surface Mount Transient Voltage Suppressors

Features

- Peak power dissipation 3000W @10 x 1000 us Pulse
- Low profile package.
- Excellent clamping capability.
- Typical I_R less than 2uA when V_{BR} above 12V.
- Glass passivated junction.
- Fast response time: typically less than 1.0ps from 0 Volts to BV min
- IEC 61000-4-2 ESD 30KV(Air), 30KV(Contact)
- ESD protection of data lines in accordance with IEC 61000-4-2
- EFT protection of data lines in accordance with IEC 61000-4-4
- Halogen free and RoHS compliant
- Lead-free finish



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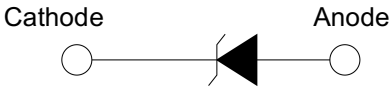
Bi-directional



Uni-directional

Mechanical Characteristics

- CASE: SMD Molded Plastic over glass passivated junction.
- Mounting Position: Any
- Polarity: by cathode band denotes uni-directional device, none cathode band denotes bi-directional device.
- Terminal: Solder plated

Maximum Ratings and Characteristics @ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	Value	Units
Peak Pulse Power Dissipation on 10/1000 us Waveform (Note 1, 2, FIG.1)	P_{PPM}	3000	W
Power Dissipation on Infinite Heat Sink at T_L=50°C	P_D	6.5	W
Peak Pulse Current of on 10/1000us Waveform (Note 1, FIG.3)	I_{PPM}	See Table 1	A
Peak Forward Surge Current, 8.3ms Single Half Sine-Wave (Note 2. 3)	I_{FSM}	300	A
Operating Junction Temperature Range	T_J	-55 to 150	°C
Storage Temperature Range	T_{STG}	-55 to 150	°C

Notes:

1. Non-repetitive current pulse, per Fig.3 and derated above T_A=25°C per Fig.2.
2. Mounted on 8.0x8.0mm^2 (0.03mm thick) Copper Pads to each terminal.
3. Measured on 8.3ms single half sine-wave, or equivalent square wave, for Unidirectional device only.

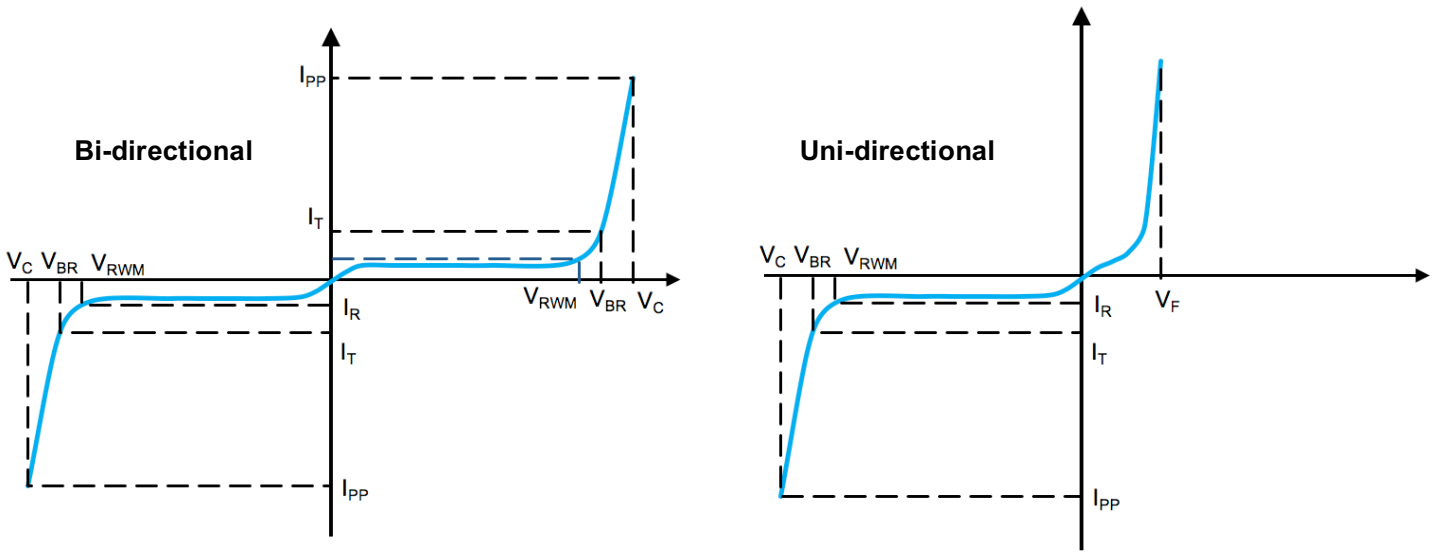
Electrical Specification @ Tamb 25°C

Type Number		Reverse Stand-Off Voltage	Breakdown Voltage Min. @I_T	Breakdown Voltage Max. @ I_T	Test Current	Maximum Clamping Voltage @I_{PP}	Peak Pulse Current	Reverse Leakage @V_{RMW}
(Uni)	(Bi)	V_{RMW}(V)	$V_{BR\ MIN}$(V)	$V_{BR\ MAX}$(V)	I_T (mA)	V_C(V)	I_{PP}(A)	I_R(uA)
SMDJ58A	SMDJ58CA	58.0	64.40	71.20	1	93.6	32.1	2

※ For Bi-directional type having V_{RWM} of 10 Volts and less, the I_R limit is double.

※ For parts without A, the VBR is ± 10% and VC is 5% higher than with A parts.

I-V Curve Characteristics



P_{PPM} **Peak Pulse Power Dissipation** - Max power dissipation

V_{RWM} **Reverse Stand-off Voltage** - Maximum voltage that can be applied to TVS without operation

V_{BR} **Breakdown Voltage** – Maximum voltage that flows though the TVS at a specified current (I_T)

V_C **Clamping Voltage** – Peak voltage measured across the TVS at a specified I_{PPM} (peak impulse current)

I_R **Reverse Leakage Current** – Current measured at V_R

V_F **Forward Voltage Drop for Uni-directional**

Ratings and Characteristic Curves (T_A=25°C unless otherwise noted)

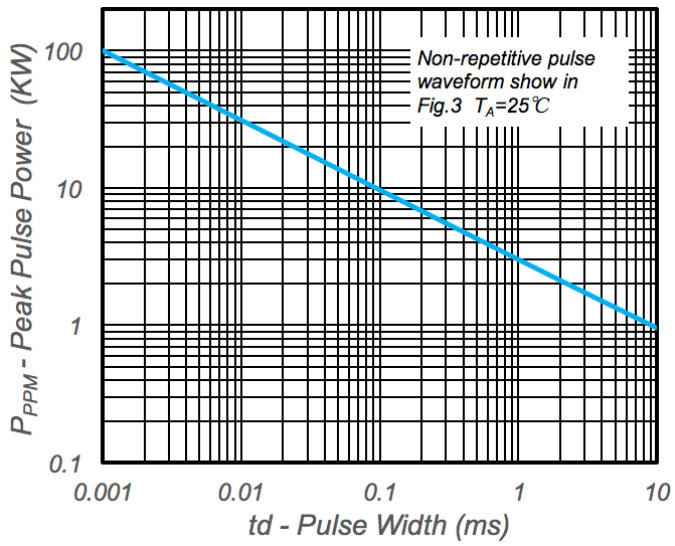


Fig.1 - Peak Pulse Power Rating

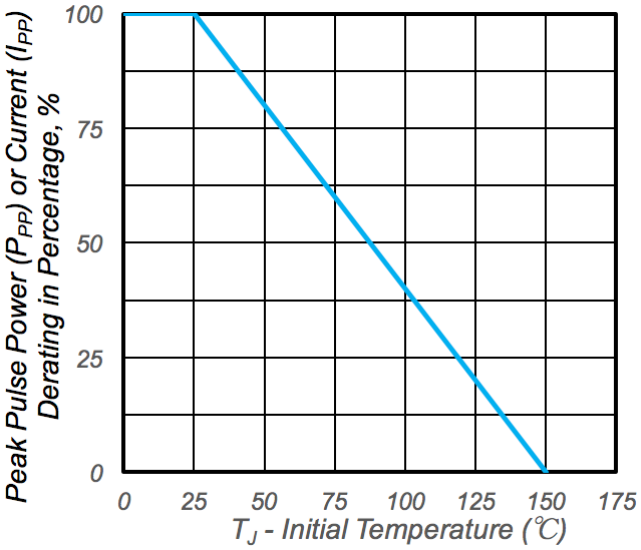


Fig.2 - Pulse Derating Cure

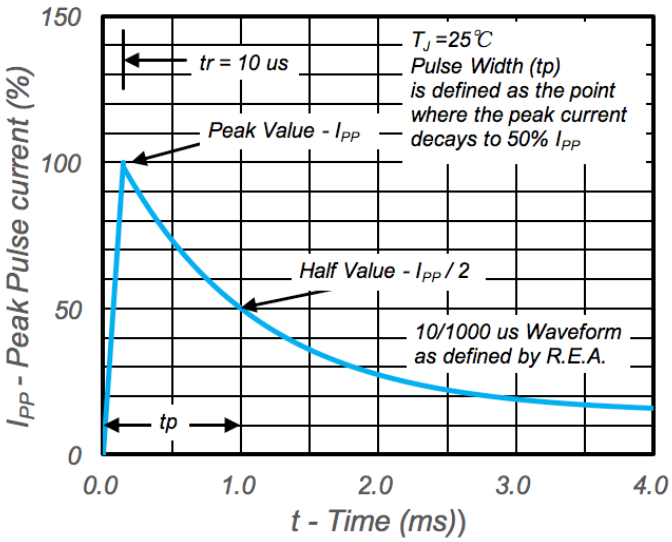


Fig.3 – Pulse Waveform

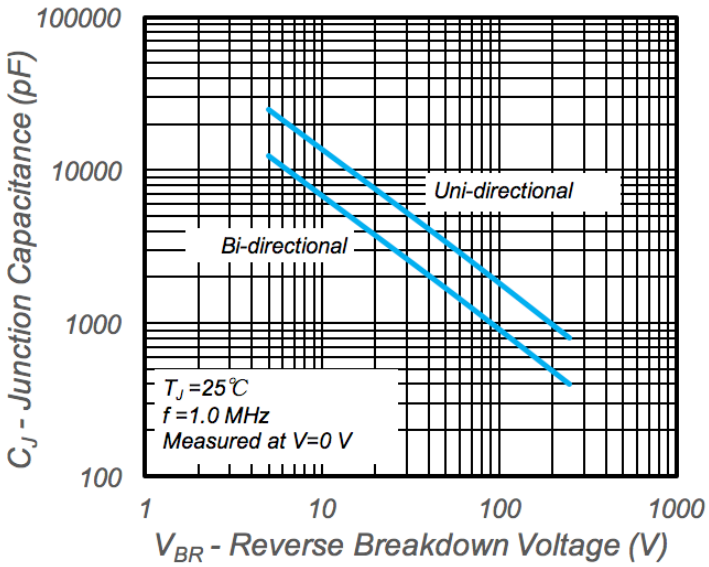
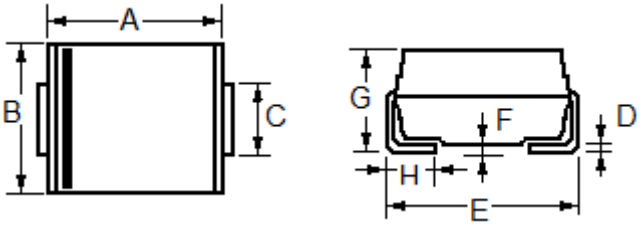


Fig.4 - Typical Junction Capacitance

Package Outline Dimensions and Pad Layouts

(SMC)



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	6.60	7.11	0.260	0.280
B	5.59	6.22	0.220	0.245
C	2.90	3.20	0.114	0.126
D	0.125	0.305	0.006	0.012
E	7.75	8.13	0.305	0.320
F	----	0.203	----	0.008
G	2.06	2.62	0.079	0.103
H	0.76	1.52	0.030	0.060